NSN 5962-00-434-3147

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-00-434-3147

Body Length:

Between 0.360 inches and 0.410 inches

Body Width:

Between 0.240 inches and 0.280 inches

Body Height:

Between 0.030 inches and 0.070 inches

Maximum Power Dissipation Rating:

150.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and negative outputs and positive outputs and w/enable and edge triggered

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Flat pack

Output Logic Form:

P-type metal oxide-semiconductor logic

Input Circuit Pattern:

1 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

0.3 volts power source

Time Rating Per Chacteristic:

80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Test Data Document:

13499-351-7503 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 flat leads

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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